NSN 5961-01-037-6457

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View Online at https://aerobasegroup.com/nsn/5961-01-037-6457 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Overall Height:** Between 0.250 inches and 0.340 inches Overall Width: 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 50.0 breakdown voltage, collector-to-emitter, with specified circuit between base and emitter and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 2.00 amperes source cutoff current and 6.00 amperes source cutoff current **Power Rating Per Characteristic:** 5.8 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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No